

Features

- Fast switching
- Extremely low on-resistance RDS(on)
- 100% single pulse avalanche energy test

Product Summary			
V _{DS}	R _{DS(on)} (mΩ) Typ	I _D (A)	Q _g (Typ)
60V	4.0 @ 10V 30A	90	30nc

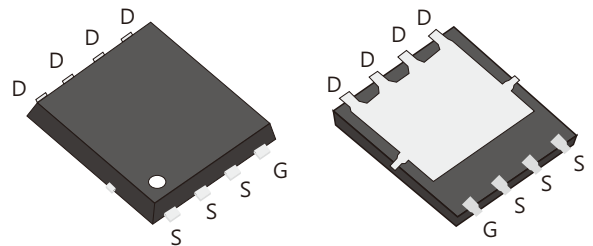
Mechanical Data

- Case:DFN5×6 Package

DFN5×6
D040N06G

Application

- Switching Application
- SR (Synchronous rectification)
- DC/DC converter
- General purpose applications



Ordering Information

Part No.	Package Type	Package	Quality(box)
D040N06G	DFN5×6	Tape & Reel	5000

Block Diagram

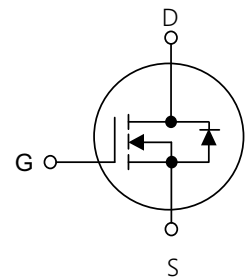


Table1 Absolute Maximum Ratings (T_c=25°C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current (Note 5)	I _D	T _c =25°C	90
		T _c =100°C	55
Pulsed Drain Current (Note 1)	I _{DM}	360	A
Single Pulse Avalanche Energy(Note 2)	E _{AS}	272	mJ
Power Dissipation T _c =25°C	P _D	78	W
Operating Junction and Storage Temperature	T _J /T _{STG}	-55~+150	°C

Table 2. Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal resistance Junction to Ambient,Max	$R_{\theta JA}$	50	$^{\circ}C/W$
Thermal resistance Junction to Case,Max	$R_{\theta JC}$	1.6	$^{\circ}C/W$

Table 3. Electrical Characteristics (T_J=25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	60	-	-	V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$	-	-	1	μA
Gate- Source Leakage Current	Forward	$V_{GS}=20V, V_{DS}=0V$	-	-	100	nA
	Reverse	$V_{GS}=-20V, V_{DS}=0V$	-	-	-100	nA
On Characteristics(Note 3)						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.6	2.5	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=30A$	-	4.0	4.8	m Ω
Dynamic Characteristics(Note 4)						
Input Capacitance	C_{ISS}	$V_{DS}=30V, V_{GS}=0V, f=1MHz$	-	2139	-	pF
Output Capacitance	C_{OSS}		-	708	-	pF
Reverse Transfer Capacitance	C_{RSS}		-	39	-	pF
Switching Characteristics (Note 4)						
Turn-On Delay Time	$t_d(on)$	$V_{DS}=30V, R_{GEN}=5\Omega$ $V_{GS}=10V, I_D=20A,$	-	6.5	-	ns
Turn-On Rise Time	t_r		-	8	-	ns
Turn-Off Delay Time	$t_d(off)$		-	38	-	ns
Turn-Off Fall Time	t_f		-	16	-	ns
Total Gate Charge	Q_G	$V_{DS}=30V, I_D=20A,$ $V_{GS}=10V$	-	30	-	nC
Gate-Source Charge	Q_{GS}		-	4.3	-	nC
Gate-Drain Charge	Q_{GD}		-	6	-	nC
Drain-Source Diode Characteristics and Maximum Ratings						
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=30A$	-	-	1.2	V
Maximum Continuous Drain-Source Diode Forward Current	I_S		-	-	90	A

Notes : 1 Repetitive Rating:Pulse width limited by maximum junction temperature
 2 L=0.3mH, Starting T_J=25°C
 3 Pulse Test: Pulse width ≤300μS, Duty cycle≤2%
 4 Guaranteed by design,not subject to production

Typical Characteristics Diagrams

Figure 1. Output Characteristics

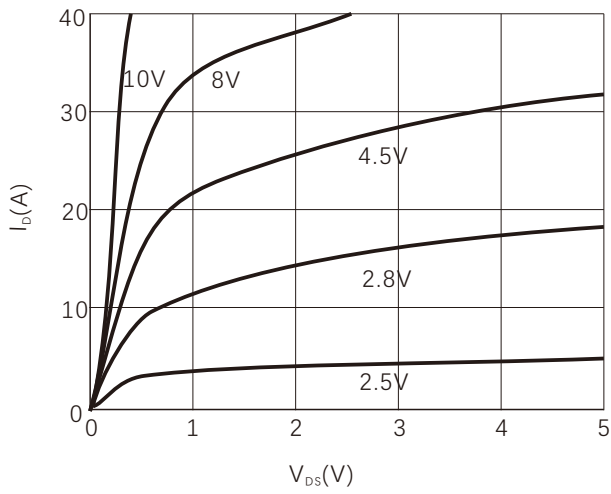


Figure 2. Normalized $R_{DS(ON)}$ vs Temperature

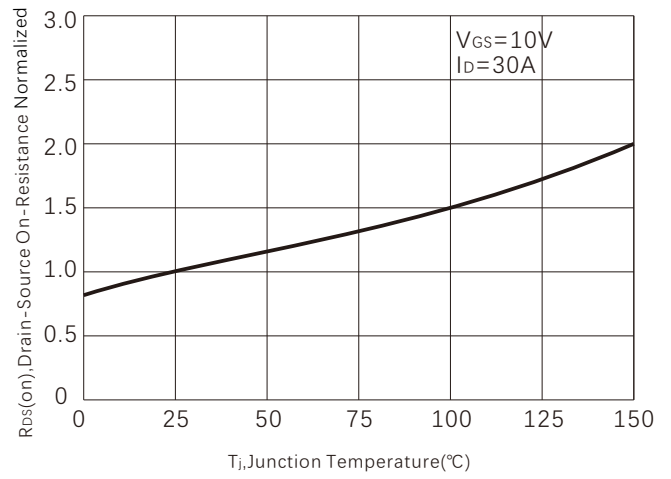


Figure 3. On-Resistance vs. Drain Current

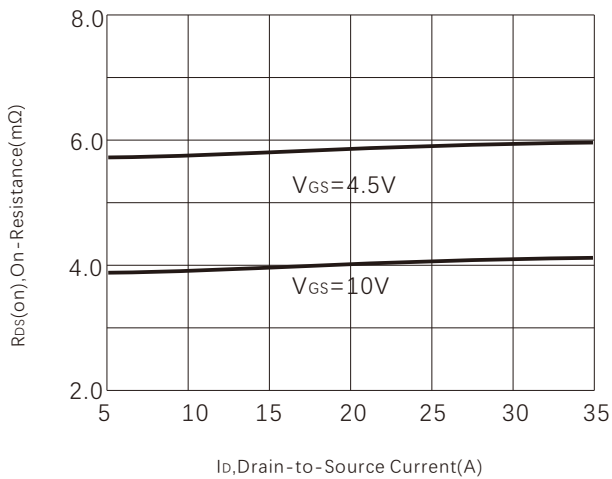


Figure 4. Capacitance

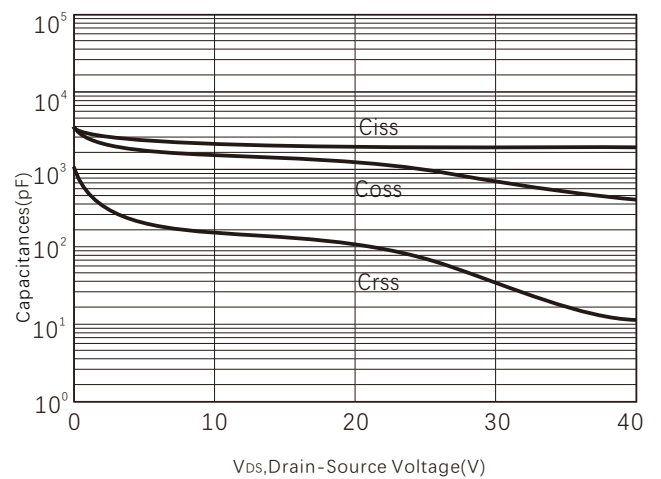


Figure 5. Gate charge

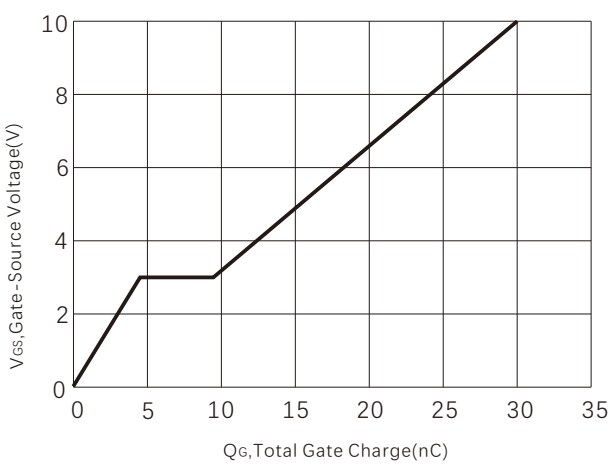


Figure 6. Source-Drain Diode Forward Voltage

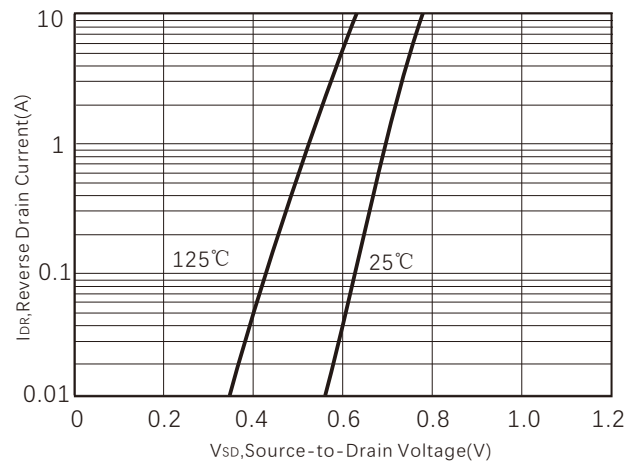


Figure 7. Maximum Drain Current vs Temperature

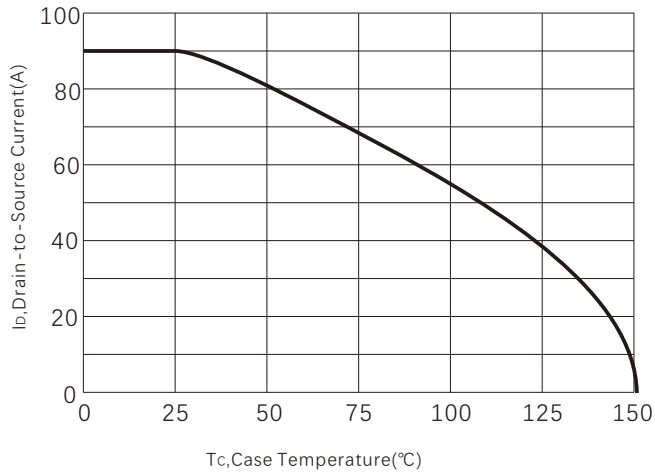


Figure 8. Power dissipation

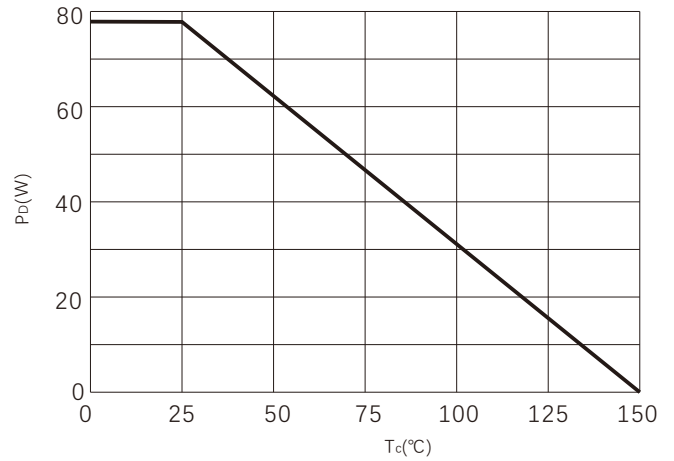


Figure 9.

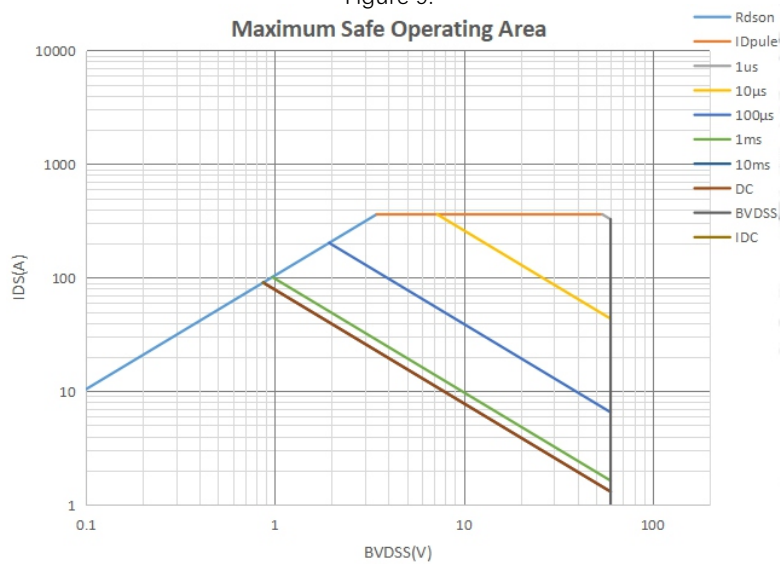
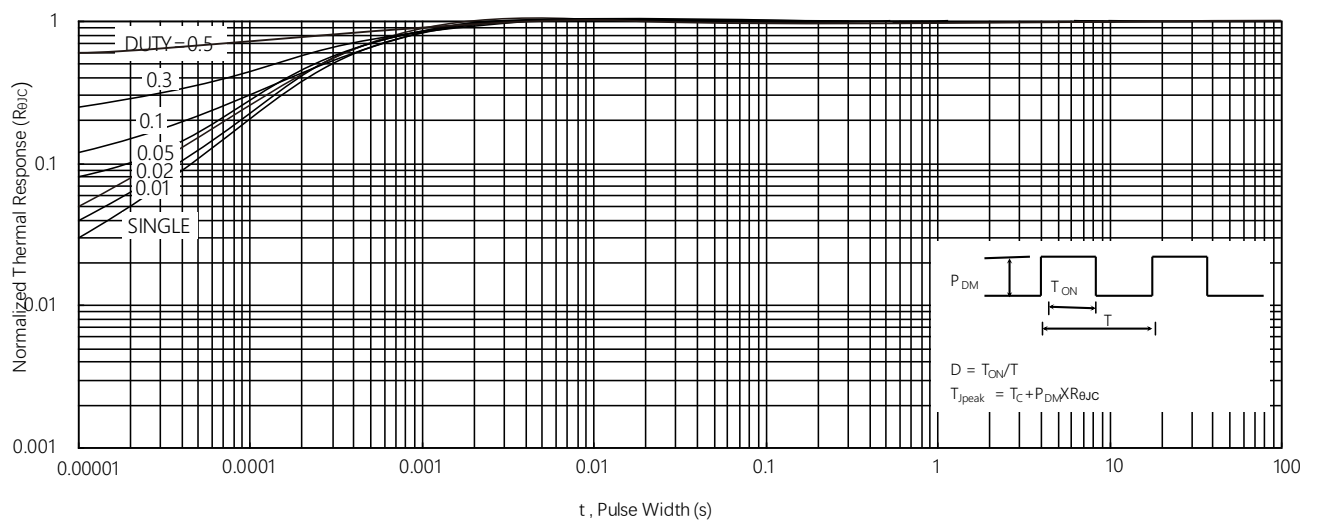
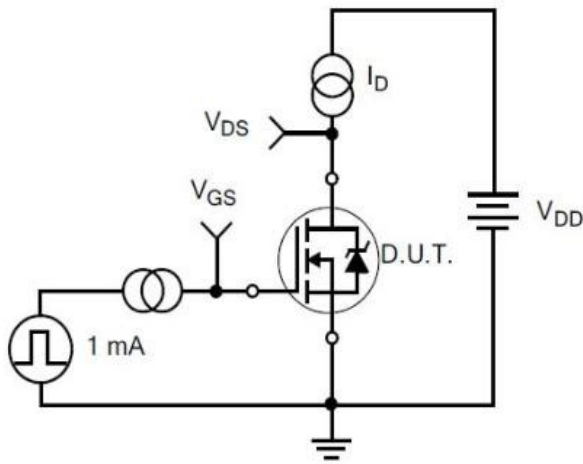


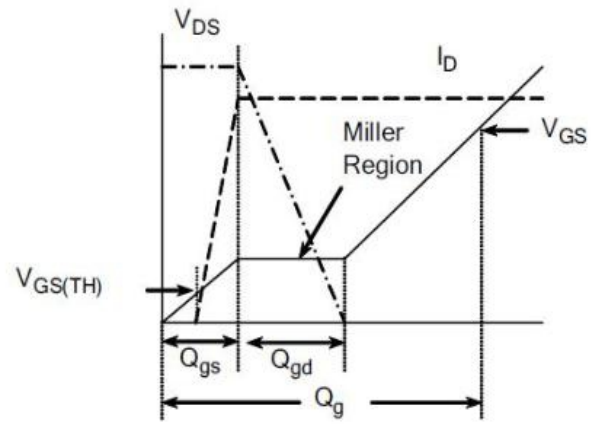
Figure 10. Normalized Maximum Transient Thermal Impedance



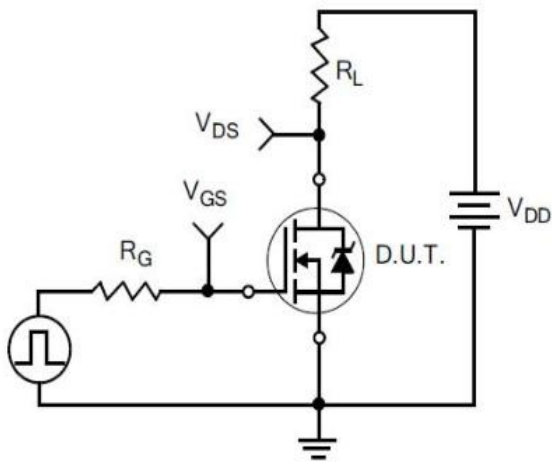
Typical Test Circuit



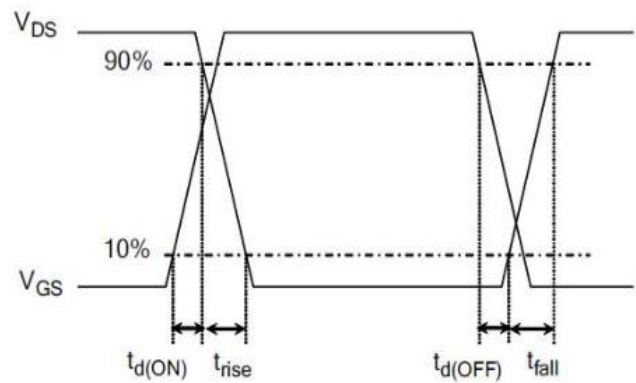
1) Gate Charge Test Circuit



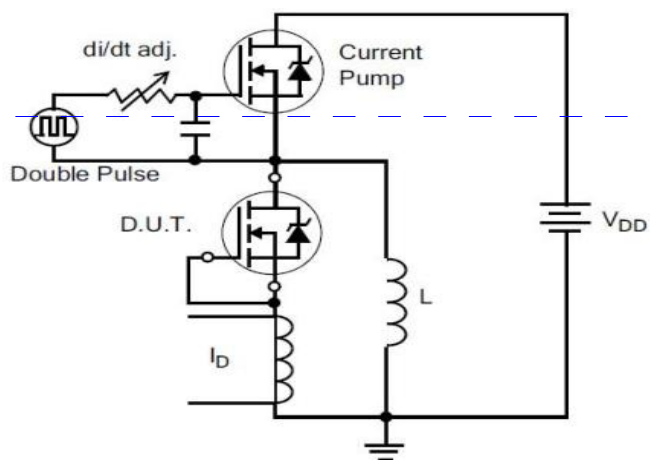
2) Gate Charge Waveform



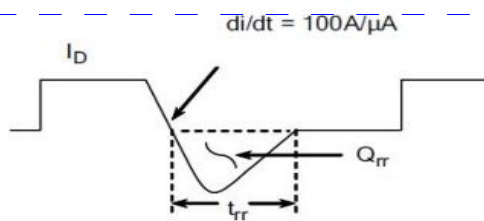
3) Resistive Switching Test Circuit



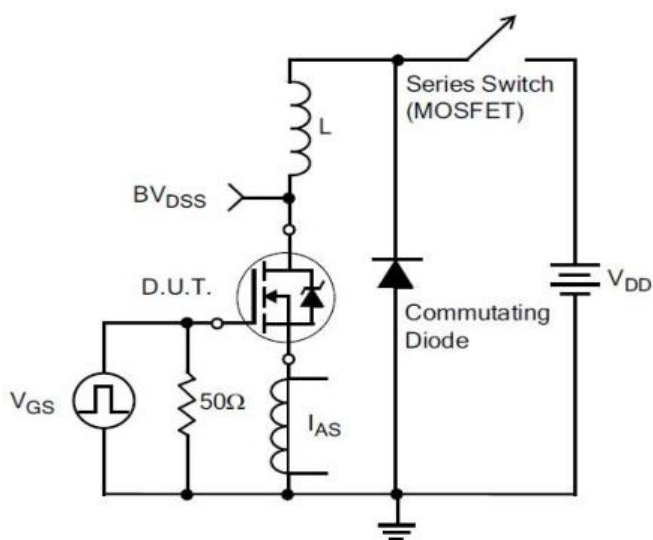
4) Resistive Switching Waveforms



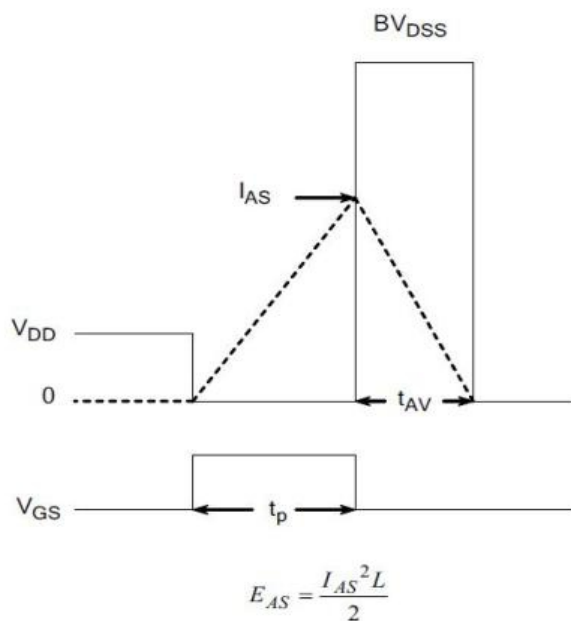
5) Diode Reverse Recovery Test Circuit



6) Diode Reverse Recovery Waveform

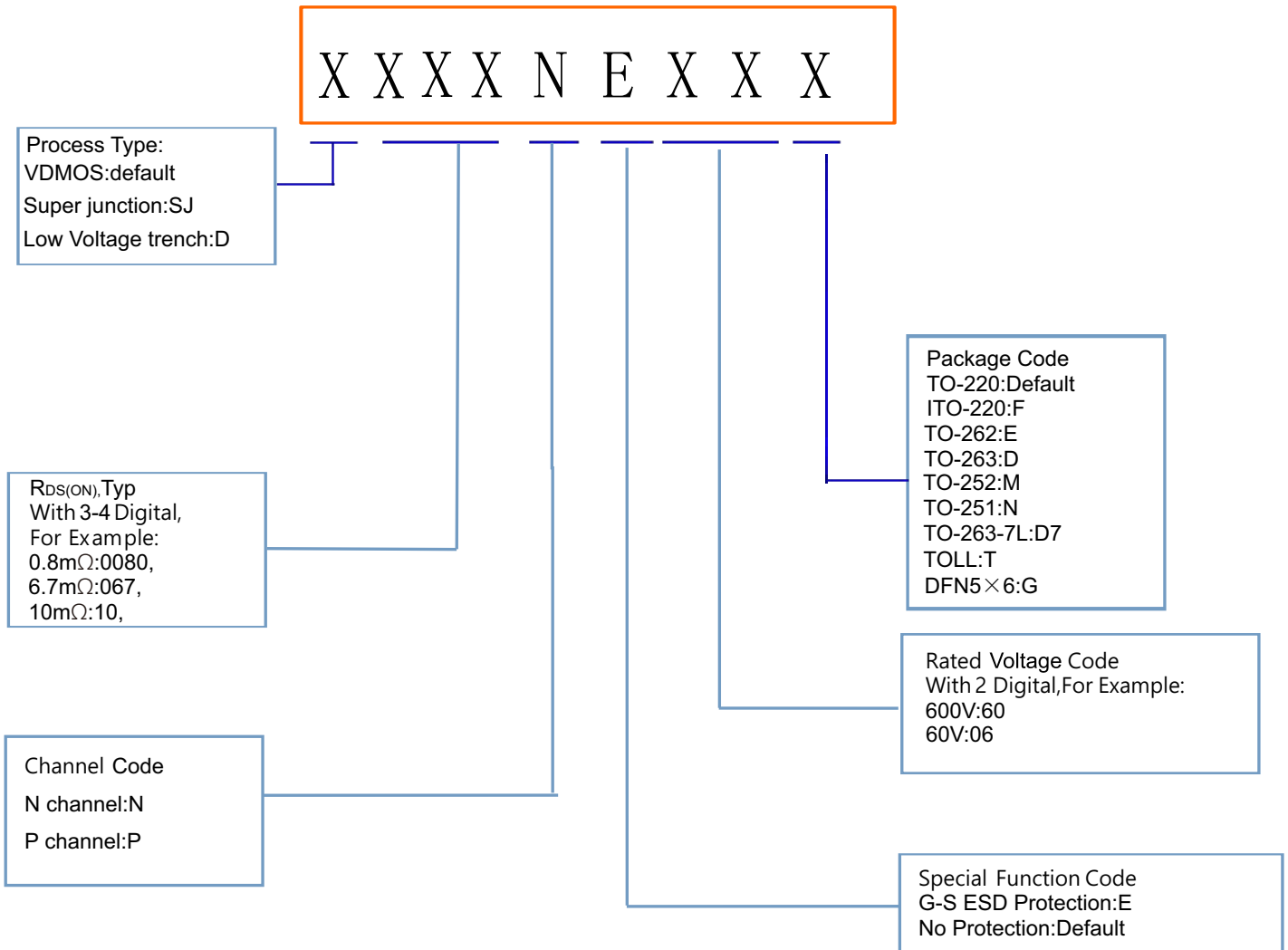


7) . Unclamped Inductive Switching Test Circuit



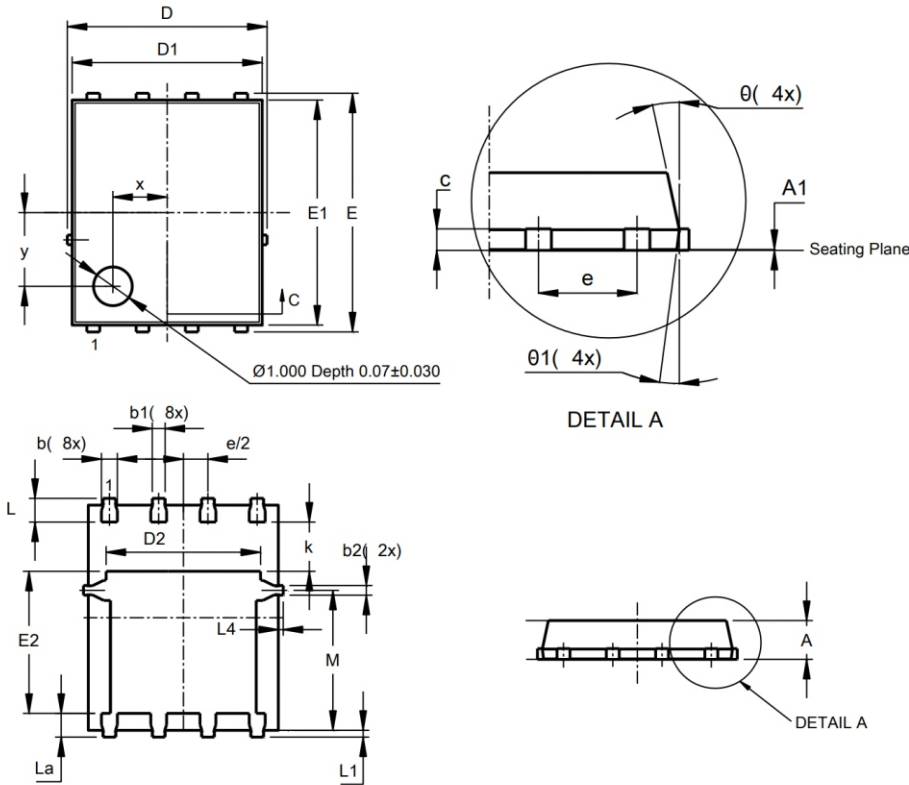
8) Unclamped Inductive Switching Waveforms

Product Names Rules



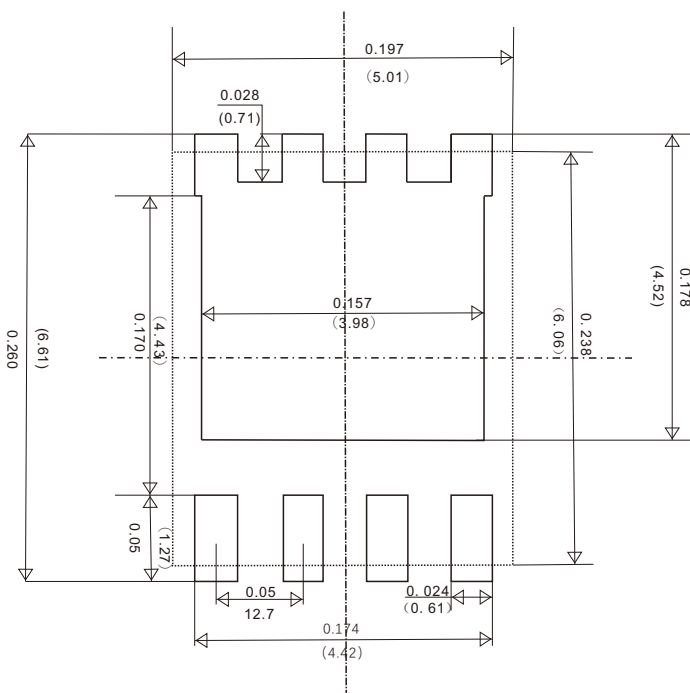
Dimensions

DFN5×6 PACKAGE OUTLINE DIMENSIONS



Dim	Min	Max	Type
A	0.90	1.10	1.00
b	0.23	0.41	0.32
b1	0.24	0.30	0.27
b2	0.16	0.32	0.23
c	0.17	0.27	0.22
D	-	-	5.01
D1	4.80	4.95	4.88
D2	-	-	3.98
E	-	-	6.06
E1	5.72	5.82	5.77
E2	3.42	3.52	3.47
k	-	-	1.33
L	0.56	0.66	0.61
La	0.57	0.67	0.63
L1	0.06	0.15	0.11
L4	-	-	0.06
M	3.00	3.20	3.08
φ	10	11	10.39

Suggested Pad Layout



Friendship Reminder

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